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# 1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>DS</sub>	Drain-source voltage	80	V
Vgs	Gate-source voltage	± 20	V
lo	Drain current (continuous) at $T_C$ = 25 ° C	90 (1)	А
ID	Drain current (continuous) at $T_C = 100$ ° C	90	А
I <sub>DM</sub> <sup>(2)</sup>	Drain current (pulsed)	360	А
Ртот	Total dissipation at $T_c = 25 \degree C$	200	W
Eas <sup>(3)</sup>	Single pulse avalanche energy	515	mJ
Tj	Operating junction temperature	55 to 175	°C
T <sub>stg</sub>	Storage temperature	- 55 to 175	C

### Notes:

<sup>(1)</sup>Limited by package

<sup>(2)</sup>Pulse width is limited by safe operating area

 $^{(3)}Starting$  Tj =25 ° C, Id = 18.5 A, Vdd = 50 V

#### Table 3: Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-pcb</sub> <sup>(1)</sup>	Thermal resistance junction-pcb	35	° C/W
Rthj-case	R <sub>thj-case</sub> Thermal resistance junction-case		° C/W

### Notes:

 $^{(1)}\!When$  mounted on FR-4 board of 1inch² , 2oz Cu



# 2 Electrical characteristics

(T<sub>CASE</sub> = 25 ° C unless otherwise specified)

Table 4: On/off states							
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
V <sub>(BR)DSS</sub>	Drain-source breakdown voltage	V <sub>GS</sub> = 0, I <sub>D</sub> = 250 µA	80			V	
	Zero gate voltage	$V_{GS} = 0, V_{DS} = 80 V$			1	μA	
IDSS	Drain current	V <sub>GS</sub> = 0, V <sub>DS</sub> = 80 V, T <sub>J</sub> =125 ° C			10	μA	
Igss	Gate-source leakage current	$V_{DS} = 0, V_{GS} = \pm 20 V$			± 100	nA	
V <sub>GS(th)</sub>	Gate threshold voltage	$V_{DS}=V_{GS},\ I_{D}=250\ \mu A$	2.5		4.5	V	
RDS(on)	Static drain-source on-resistance	$V_{GS}$ =10 V, $I_{D}$ = 45 A		3.3	4	mΩ	

Table 5: Dynamic		_	_	
	Table	e 5:	Dvn	namic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Ciss	Input capacitance		-	6340	-	pF
Coss	Output capacitance	$V_{GS} = 0, V_{DS} = 40 V,$ f = 1 MHz	-	1195	-	pF
Crss	Reverse transfer capacitance		-	105	-	pF
Qg	Total gate charge		-	96	-	nC
Q <sub>gs</sub>	Gate-source charge	V <sub>DD</sub> = 40 V, I <sub>D</sub> = 64 A, V <sub>GS</sub> = 10 V	-	30	-	nC
Q <sub>gd</sub>	Gate-drain charge	VGS - 10 V	-	26	-	nC

Table 6: Switching times

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>d(on)</sub>	Turn-on delay time		-	26	•	ns
tr	Rise time	$V_{DD} = 40 \text{ V}, \text{ I}_{D} = 45 \text{ A R}_{G} = 4.7 \Omega,$		51	-	ns
t <sub>d(off)</sub>	Turn-off-delay time	V <sub>GS</sub> = 10 V	-	82	-	ns
t <sub>f</sub>	Fall time		-	44	-	ns

#### Table 7: Source drain diode

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>SD</sub>	Source-drain current		-		90	А
Isdm <sup>(1)</sup>	Source-drain current (pulsed)		-		360	А
V <sub>SD</sub> <sup>(2)</sup>	Forward on voltage	$V_{GS} = 0, I_{SD} = 90 \text{ A}$	-		1.2	V
trr	Reverse recovery time		-	58		ns
Qrr	Reverse recovery charge	I <sub>SD</sub> = 64 A, di/dt = 100 A/µs, V <sub>DD</sub> = 60 V, T <sub>i</sub> = 150 ° C	-	92		nC
Irrm	Reverse recovery current	$v_{DD} = 00 v, t_j = 150 C$	-	3.2		А

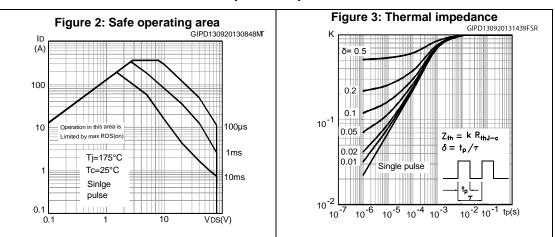
#### Notes:

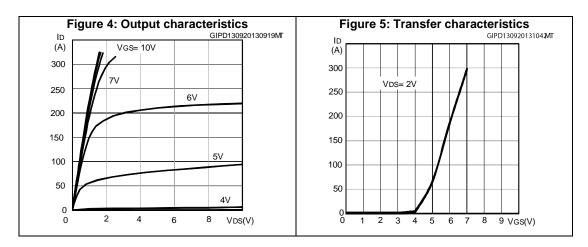
 $^{(1)}$  Pulse width is limited by safe operating area  $^{(2)}$  Pulse test: pulse duration = 300  $\mu$  s, duty cycle 1.5%

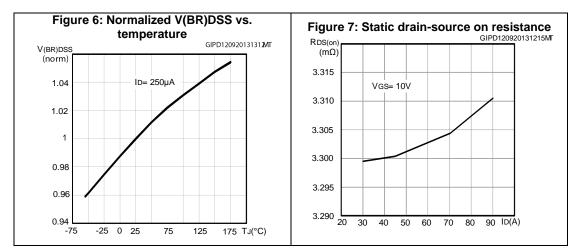
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## 2.1 Electrical characteristics (curves)



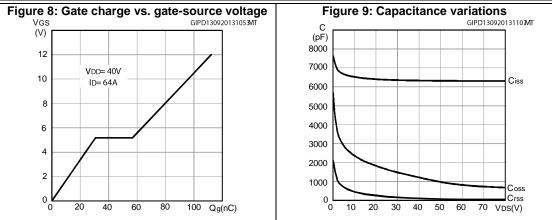


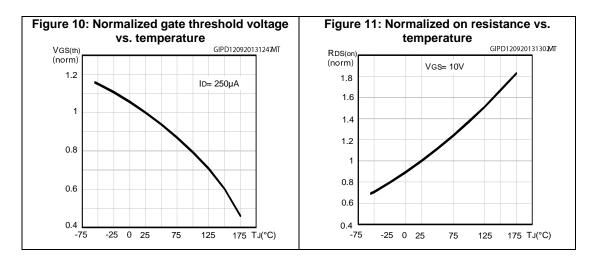


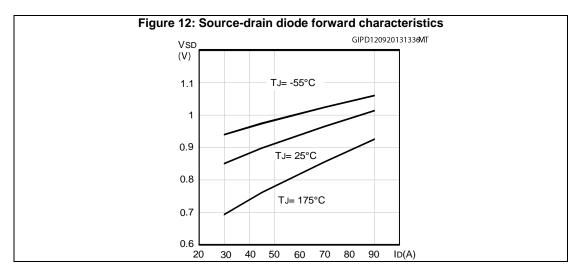
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### **Electrical characteristics**

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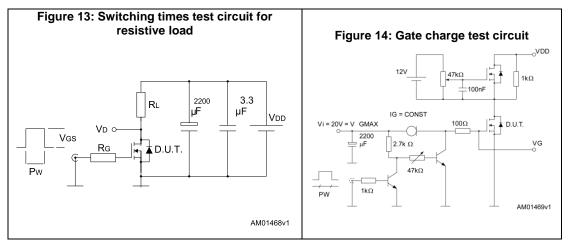


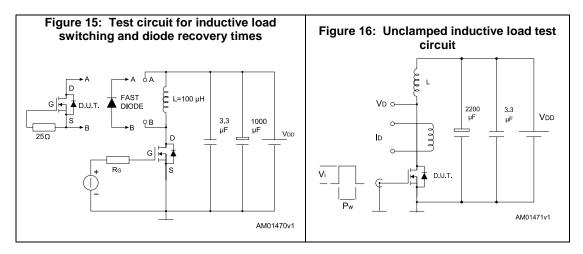
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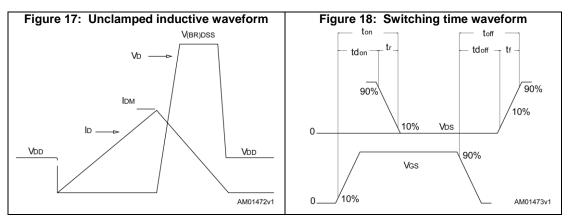
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# 3 Test circuit







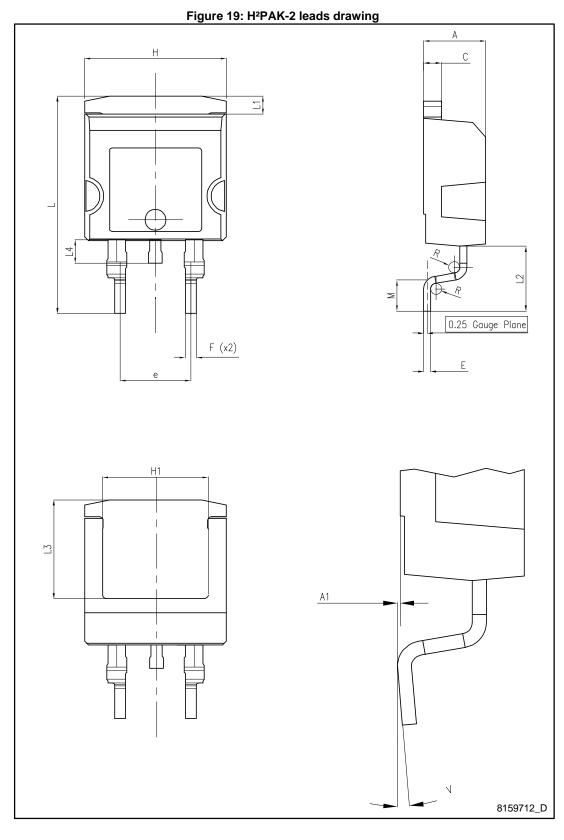
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# 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.



## 4.1 H2PAK-2 mechanical data





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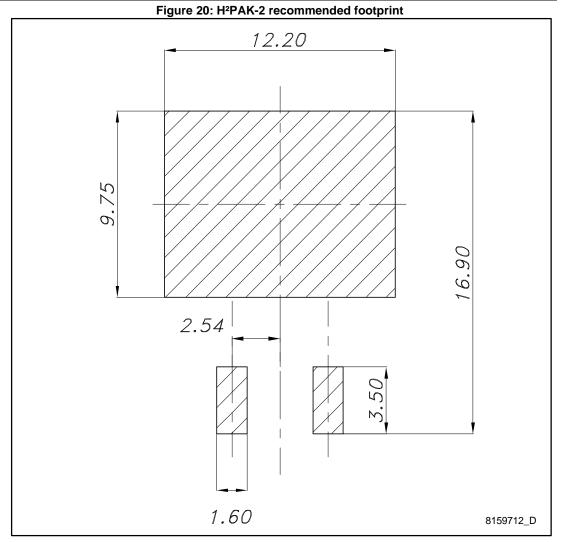
## Package mechanical data

## STH140N8F7-2

chanical data SI FI 140N0F7-2					
	Table 8: H <sup>2</sup> PAK-2 lea	ds mechanical data			
Dim.	mm				
Dim.	Min.	Тур.	Max.		
А	4.30		4.80		
A1	0.03		0.20		
С	1.17		1.37		
е	4.98		5.18		
E	0.50		0.90		
F	0.78		0.85		
Н	10.00		10.40		
H1	7.40		7.80		
L	15.30	-	15.80		
L1	1.27		1.40		
L2	4.93		5.23		
L3	6.85		7.25		
L4	1.5		1.7		
М	2.6		2.9		
R	0.20		0.60		
V	0°		8°		

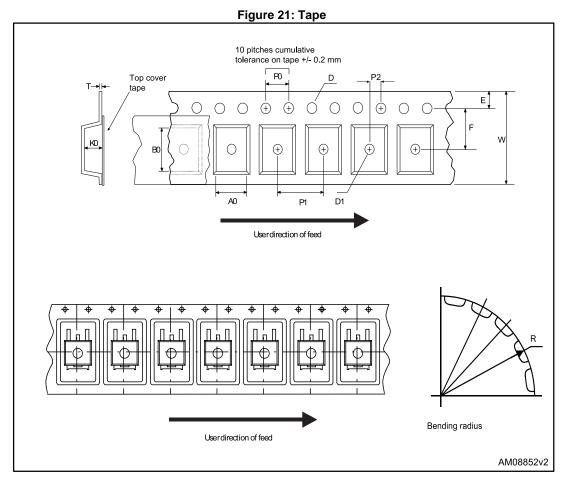
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# 5 Packaging mechanical data





## Packaging mechanical data

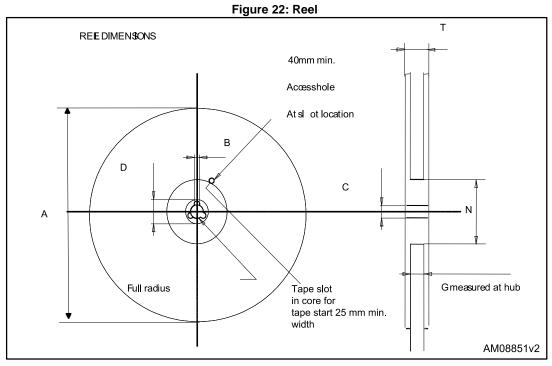


Table 9: Tape and reel mechanical data

	Таре	•		Reel	
Dim.	n	ım	Dim.	r	nm
Dim.	Min.	Max.	Dini.	Min.	Max.
A0	10.5	10.7	A		330
B0	15.7	15.9	В	1.5	
D	1.5	1.6	С	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
К0	4.8	5.0	Т		30.4
P0	3.9	4.1			
P1	11.9	12.1	Bas	se qty	1000
P2	1.9	2.1	Bul	k qty	1000
R	50				
Т	0.25	0.35			
W	23.7	24.3			



# 6 Revision history

Table 10: Document revision history

Date	Revision	Changes
25-Aug-2014	1	First release. Part numbers STF140N8F7 and STP140N8F7 previously included in the datasheet DocID023888.
10-Oct-2014	2	Updated Figure 3: "Thermal impedance"



### STH140N8F7-2

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